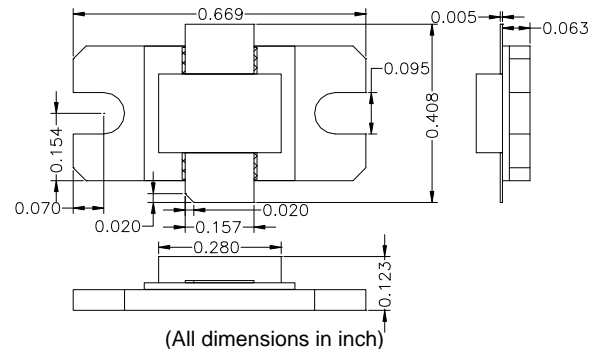


### DESCRIPTION

AMCOM's AM150MX-CU-R is a part of the CU series of GaAs MESFETs. This part has a total gate width of 15mm. The AM150MX-CU-R is designed for high power microwave applications, operating up to 6GHz. The CU series is in a specially designed ceramic package with straight leads and flange in a drop-in mounting style. The flange at the bottom of the package serves simultaneously as DC ground, RF ground and thermal path. This FET is RoHS Compliant.



### FEATURES

- High Frequency Operation up to 6GHz
- High Gain and High Power,  $P_{1dB}=36.5\text{dBm}$  @3.5GHz
- Low Cost Ceramic Package
- Copper Tungsten Carrier for Effective Heat Removal

### APPLICATIONS

- Wireless Local Loop Network
- PCS Base Stations
- WLAN, Repeaters & HYPERLAN
- C-Band VSAT

### RF PERFORMANCE @ 3.5 GHz, ( $V_{ds} = 7\text{V}$ , $I_{ds} = 0.5 I_{dss}$ )

Parameters	MIN	TYP
$P_{1dB}$ * (dBm)	35.5	36.5
Eff @ $P_{1dB}$	30%	37%
Small Signal Gain (dB)	9	10
IP3 (dBm)	48	50

\* Power typically remains the same as frequency changes.

### ABSOLUTE MAXIMUM RATING

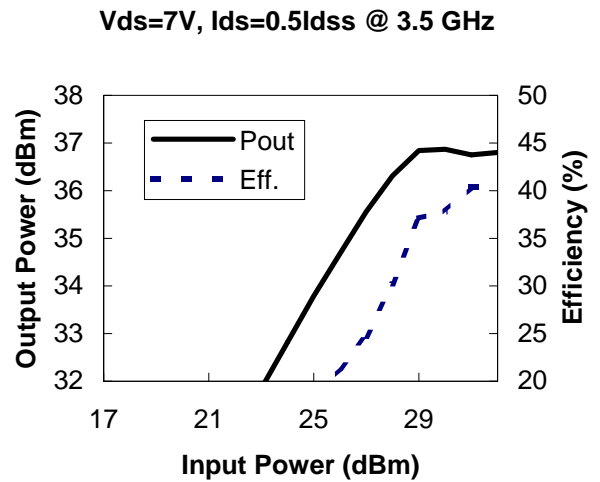
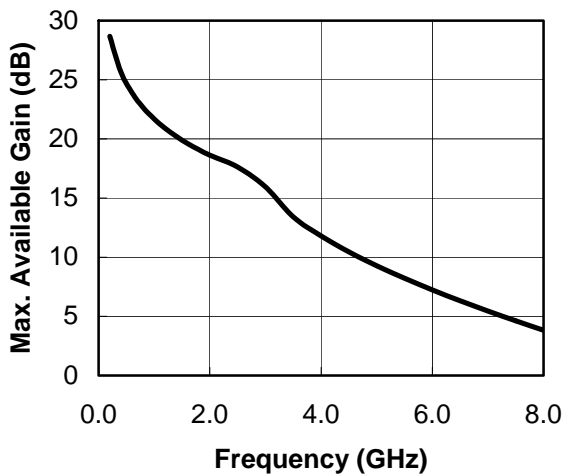
Parameters	Sym	Rating
Drain-Source Voltage (V)	$V_{ds}$	9
Gate-Source Voltage (V)	$V_{gs}$	-5
Drain Current (mA)	$I_{ds}$	4750
Continuous Dissipation At Room Temp. (W)	$P_t$	24
Operating Temp. ( $^{\circ}\text{C}$ )	$T_A$	-55 to +85
Max. Channel Temp. ( $^{\circ}\text{C}$ )	$T_{ch}$	+175

### DC PARAMETERS

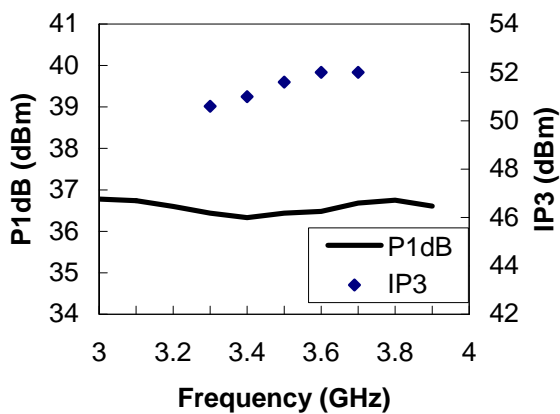
Parameters	Conditions	MIN	TYP	MAX
Saturation Current $I_{dss}$ (mA)	$V_{ds} = 3\text{V}$ $V_{gs} = 0\text{V}$	2550	3500	4750
Pinch-off Voltage $V_p$ (V)	$V_{ds} = 3\text{V}$ $I_{ds} = 2.5\% I_{dss}$	-2.6	-2	-1.0
Drain to Gate Breakdown Voltage $BV_{gd}$ (V)	$I_{dg} = 1\text{mA/mm}$	11	15	
Drain to Source Voltage $V_{ds}$ (V)	Mounted on Heat Sink		7	
Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ )		6		

**S-Parameters for AM150MX-CU-R @ 7V / 0.5 I<sub>dss</sub> (s2p file downloadable from the web)**

Freq (MHz)	MAG (S11)	ANG(S11)	MAG (S21)	ANG(S21)	MAG (S12)	ANG(S12)	MAG (S22)	ANG(S22)
1000	0.951	-180.0	1.991	72.1	0.014	-3.6	0.838	173.6
2000	0.927	166.0	1.370	44.3	0.019	-16.8	0.782	164.8
3000	0.849	146.4	1.640	5.5	0.034	-40.8	0.634	154.1
4000	0.556	84.0	2.734	-69.7	0.080	-101.0	0.349	146.1
5000	0.831	-105.6	1.547	162.7	0.060	146.0	0.527	-119.1
6000	0.959	-148.4	0.402	105.3	0.020	102.4	0.855	-148.9
7000	0.979	-162.6	0.154	78.5	0.010	87.9	0.934	-162.1
8000	0.986	-170.7	0.078	61.4	0.007	81.4	0.962	-170.2



V<sub>ds</sub>=7V, I<sub>ds</sub>=0.5I<sub>dss</sub> Test CKT @ 3.5 GHz



Specifications subject to change without notice.